D ynam ics of Spontaneous M agnetization R eversal in Exchange B iased H eterostructures

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The dependence of therm ally induced spontaneous magnetization reversal on time-dependent cooling protocols was studied. Slower cooling and longer waiting close to the Neel temperature of the antiferrom agnet (T_N) enhances the magnetization reversal. Cycling the temperature around T_N leads to a thermal training e ect under which the reversal magnitude increases with each cycle. These results suggest that spontaneous magnetization reversal is energetically favored, contrary to our present understanding of positive exchange bias.

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Exchange bias (EB) arises when a ferrom agnet/antiferrom agnet (FM /AF) heterostructure is cooled in a magnetic eld (H $_{\rm F\,C}$) below the Neel temperature $T_{\rm N}$ of the AF^{1,2,3}. EB is manifested as a shift of the hysteresis loop along the eld axis by an amount H $_{\rm E\,B}$, dubbed the exchange bias eld. This phenom enon has been intensely studied in the past ten years due to its signi cance in providing a magnetic reference in spin valve devices⁴. M ore fundamentally, EB is also of physical im portance for understanding competing interactions in coupled magnetic materials. A rich variety of physical phenom ena are associated with EB, including thermal stability⁵, positive EB⁶, training e ect^{7,8}.

W e recently dem onstrated that a thin exchange biased FM layer can fully reverse its magnetization to point against a constant H_{FC} during cooling⁹. Sim ilar behavior has been observed in fermin agnet Gd-Co¹⁰ and Co/Gdmultilayer system s¹¹, which results from two antiferrom agnetically coupled spin species com peting to align with the eld. In the present case, a prerequisite for spontaneous m agnetization reversal is positive EB, where the hysteresis loop is shifted in the direction of H $_{\rm FC}$ ⁶. Posit ive EB arises when H_{FC} is large enough to overcome the antiferrom agnetic interfacial coupling, thus aligning uncompensated AF moments along the eld. In other words, positive EB requires $\mathbf{E}_{intj} < \mathbf{E}_{AF Z eem an} \mathbf{j}$ where E $_{\rm int}$ and E $_{\rm A\,F}$ $_{\rm Z\,eem\,\,an}$ are the interfacial coupling energy and the Zeem an energy of uncom pensated AF moments, respectively. Negative EB arises when H_{FC} is small enough that the interfacial coupling forces AF moments to align antiparallel with the eld. W hen positively exchange biased, a FM spontaneously reverses its magnetization when F_{int} j> F_{FM} zeem an j. This implies \mathbf{E}_{FM} zeeman j< \mathbf{E}_{AF} zeeman j or equivalently $j_{m_{FM}} j < j_{m_{AF}} j$, where m_{FM} and m_{AF} are FM and uncom pensated AF m agnetic m om ents, respectively. H ow ever, our experiment indicated $m_{FM} j >> m_{AF} j be$ cause there was no evidence of a signi cant vertical shift of the low-tem perature hysteresis loop (a signature of pinned AF moments), or a reduction of the saturation m agnetization (a signature of unpinned AF m om ents)¹². Therefore, spontaneous magnetization reversal seem senergetically unfavorable within the existing fram ework of



FIG.1: (Color online) (a) M vsT of N i/FeF₂ norm alized by M s with H $_{\rm FC}$ = 0:1 kO e. The dashed line m arks $T_{\rm N}$ = 78K. The red crossed squares m ark the initial and nalnorm alized m agnetization of the sam e cooling procedure from 150K to 10K but without m easurem ent at interm ediate tem peratures. (b) M agnetic hysteresis at T = 10K after cooling with H $_{\rm FC}$ of -0.1 kO e (black), 0.1 kO e (red) and 1 kO e (blue) at 10K /m in.

exchange bias. A lower energy state would have positive FM and negative AF moments, corresponding to negative EB, rather than observed positive EB. This contradiction im plies that either spontaneous reversal is a novel metastable state, or our present understanding of positive EB is incomplete.

This work reports slow dynamics and thermal training of the spontaneous reversal e ect. We show that a slow cooling rate enhances the magnetization reversal magnitude, and that reversal is strongly related to dynamic processes around $T_{\rm N}$. Relaxation of the system at $T_{\rm N}$ over a long period of time causes increased reversal at low temperatures. Successive thermal cycling about $T_{\rm N}$ allows the system reach a global equilibrium state. These results show that spontaneous reversal is energetically favored rather than a metastable state as predicted by the existing positive exchange bias model. Possible directions for a modil ed theory of positive exchange bias are suggested.

The same Ni(3nm)/FeF₂ (30nm) sample on a MgF₂ substrate was studied as in our previous work⁹. FeF₂ is an AF with $T_N = 78$ K, and grow sepitaxially untwinned in the (110) direction on MgF₂ (110) substrates¹³. The FM exhibits uniaxial anisotropy with the easy axis parallel to FeF₂ [001] (the spin axis of the AF). The magnetic



FIG.2: (Color online) (a) $M = M_s$ as function of uniform cooling speed dT=dt for $H_{FC} = 0.1 \text{ kOe}$. The line is a t to an exponential function. (Inset) Temperature vs time for uniform cooling speeds of 2.5 (blue) and 0.6 K/m in (red). (b) $M = M_s$ as a function of wait time at temperatures $T_w = 75$ (green), 80 (black), and 85 (red) K for $H_{FC} = 0.1 \text{ kOe}$. (Inset) Schem atic of this cooling protocol. Lines are a guide to the eye.

eld was always applied along the easy axis of the FM. Prior to cooling, the FM was saturated with a 5kO e eld, well above the 150K coercive eld of $H_c = 0.35 \text{ kOe}$, then reduced to ${\rm H}_{\,{\rm F}\,{\rm C}}$. Fig. 1(a) shows the thermally induced m agnetization reversal in $H_{FC} = 0.1 \text{ kOe}$. Hysteresis m easurem ents at T = 10K nd negative EB for 025kOe Η_{FC} 0:1kOe, positive EB at H $_{\rm FC}$ > 0.5 kOe, and coexistence for $-0.1 \text{ kOe} < H_{FC} < 0.5 \text{ kOe}$ (Figure 1(b)). $\mathcal{H}_{EB} j = (3.9 \quad 0.1)$ kO e for all cooling elds. Coexistence of positive and negative EB at an intermediate H_{FC} has been interpreted as the AF breaking into \dom ains" with uncom pensated m om ents of either $sign^{13}$. W hen the lateral size of these \dom ains" is much larger than the FM domain wall width, they independently induce either positive or negative EB in the FM, causing the experim entally observed double hysteresis loop. Since only positive EB is essential for spontaneous reversal, partial reversal was observed for H $_{\rm F\ C}$ associated coexistence (Fig. 1 (a)).

Two di erent cooling protocols were used to inves-

tigate the time dependence of the reversal magnitude M = M (T = 10 K) M (T = 150 K). We only consider H_{FC} = 0.1 kOe, for which the magnetization reverses by about 50% upon cooling. The rst protocol cooled the sample from T = 150K to 10K with two decades (0.1-10 K/m in) of uniform cooling speeds (Fig. 2 (a) inset). The second protocol cooled the sample at 10K/m in from 150K to an interm ediate tem perature T_w, where the tem – perature was held constant for a time , then cooled to 10K at 10K/m in (Fig. 2 (b) inset). For both protocols, M (T = 10 K) was measured after the sample tem perature stabilized at 10K.

Fig. 2 (a) shows that slower cooling leads to a larger j M j. W ith the present de nition, M = 2 im - p lies complete magnetization reversal. W ith the largest cooling speed of 10 K / m in, the FM reverses by M =

 $0.9M_{\rm S}$. W hen cooled at 0.1 K/m in, jM jincreases by $0.2M_{\rm S}$. M oreover, the dependence of M on the cooling speed is well t by an exponential function M = M₀ + A exp(dT=dt). This t im plies M of -0.88 and 1.15M_S in the limits of in nite and zero cooling speed,

respectively.

The second cooling protocol dem onstrates that jM j is sensitive to the time spent with T T_N . The dependence of M on the wait temperature T $_{\rm w}$ shows the largest reversal for $T_w = 80 \text{ K}$, closest to T_N (Fig. 2). As increases beyond 35 m in, jM jincreases from $0.86M_{\rm S}$ to $1.18M_{\rm S}$. For $T_{\rm w}$ = 85K, jM jonly changes by 0.07M $_{\rm S}$ after waiting for 50 m inutes. For $T_{\rm w}$ = 75K , jM j saturates after 15 m inutes at 1:05M $_{\rm S}$. This Tw-dependent behavior was not observed when waiting at the reversaltem perature (T = 63 K). The results from these two cooling protocols show that spontaneous magnetization reversal exhibits slow dynamics with a relatively long time scale. The fact that the dynam ics are most pronounced around T_N hints that this e ect depends on the establishm ent of AF dom ain states.

Several tests were performed to ensure that the dynam ics were not experim ental artifacts. First, measuring the magnetic moment via SQUD involves moving the sam ple through the SQUID coils by 4 cm, thus subjecting the sample to magnetic eld inhomogeneity. To exclude this as an artifact, the cooling procedure used to obtain the data of Fig. 1 was repeated, but measuring only the initial and nalthem agnetization values, rather than at several interm ediate tem peratures. The sam ple was thus only exposed to eld inhom ogeneity at these extrem e tem peratures. The reversalm agnitude only differs by 3 10^{4} M $_{\rm S}$ between these two methods, which is negligibly sm all. Tem perature uctuations during cooling are another source of potential signal artifacts. To investigate this, the sample was heated from 10K to a tem perature T_x , then cooled back down to 10K.W hen 80K, M varies by no more than $0.01M_{\odot}$, too Τx sm all to account for any M variation found earlier (Fig. 3). W hen T_x > 80 K, a signi cant additionalm agnetization reversal was observed (m ore below). These checks dem onstrate that the tim e-sensitivity of spontaneous re-



FIG.3: (C olor online) N orm alized m agnetization M =M $_{\rm S}$ was m easured after each step of the three-step therm al cycle: (1) cool from T = 150 K to 10 K (m agenta cross); (2) warm to T_x (40-110 K) (red triangles); (3) cool back down to 10 K (blue squares). M =M $_{\rm S}$ was reversible for T_x < 80 K, but irreversible above 80 K. The dashed line separates these two regimes, and is close to T_N. The lines are schem atics of the m easurem ent sequence.

versal is not an experim ental artifact but rather is intrinsic to the system, and clearly related to the AF phase transition. Larger reversal for slower cooling rates and longer wait times around $T_{\rm N}\,$ suggests that spontaneous reversal is therm odynam ically favorable.

The slow evolution of the system toward a larger reversal in plies the presence of large energy barriers. The additional large reversal during therm al cycling above 80 K (Fig. 3) suggests that the system can overcom e this energy barrier by therm all activation. Therm all training refers to successive m agnetization reversal when the system is cycled above and below ${\rm T}_{\rm N}$. W ith the FM saturated, the sample was rst cooled in $H_{FC} = 0:1 \text{ kO} \text{ e from}$ 150K to 10K at 0.1K /m in, followed by heating to 150K, just below the tem perature for the FM to reverse back along the eld direction (Fig. 1). A fter that, the sam ple was cycled between 150K and 10K. The magnetic eld was held constant at H $_{FC}$ = 0:1 kO e throughout the therm alcycles. The FM reverses with each additional cooling (with decreasing increm ental reversalm agnitude) until the totalm agnetization reversal reaches $1.8M_{\rm S}$, signi cantly larger that the initial reversal for any cooling speed or wait time (Fig. 4(a)).

Fig. 4 (b) shows the dependence of M (10K) on the number of cycles N for di erent H $_{\rm FC}$ and cooling speeds. For all cases, they follow an exponential dependence, M $_{\rm N}$ (10K) = M $_1$ + (M $_{\rm S}$ M $_1$) exp(N =), where M $_1$ is the convergent M (10K) when N ! 1, and is a characteristic cycle number for each H $_{\rm FC}$ and cooling speed. M $_{\rm N}$ (10K) for N = 0 is de ned as M $_{\rm S}$. M $_1$ appears to be linearly dependent on H $_{\rm FC}$ for constant cooling speed (Fig. 4 inset). Larger H $_{\rm FC}$ results in smaller , which m eans a faster approach to M $_1$. This makes qualitative sense because a larger magnetic eld should facilitate reversal by low ering the energy barrier, so that m ore AF



FIG.4: (Color online) (a) Norm alized m agnetization M =M $_{\rm S}$ was measured as the temperature was cycled between 150K and 10K in a 0.1kO e eld. N ine cycles were conducted. (b) Norm alized m agnetization M =M $_{\rm S}$ at T = 10 K after each therm al cycle between 150K and 10K as a function of the number of cycles N . D i erent cooling parameters were used, H $_{\rm F\,C}$ = 100 e (blue), 500 e (black), 1000 e (red) with 10K /m in cooling/heating rate, and H $_{\rm F\,C}$ = 1000 e with 0.1K /m in (green). The lines are a guide to the eye. (Inset) A symptotic m agnetization M $_1$ =M $_{\rm S}$ at high cycling number N obtained by exponential tting, as a function of H $_{\rm F\,C}$. The red line is a linear t.

m om ents are aligned in the eld direction.

These experiments suggest that it is energetically favorable for the FM to reverse against H FC, albeit counterintuitive since $j_{MFM} j >> j_{AF} j$. This behavior cannot be explained simply by the competition between the Zeem an energy and interfacial coupling. A new mechanism for determ ining the sign of AF uncom pensated mom ents is necessary to explain the features we observe experim entally. Consider that $(M_S M (10 K))=2M_S$ gives the percentage of sample that exhibits positive EB at 10K for an intermediate H_{FC} . For $H_{FC} = 0:1 \text{ kOe}$, the sample is nearly 90% positively exchange biased at 10K after 6 therm alcycles at 0.1K /m in. The interfacial coupling energy in this sample is E $_{\rm int}$ = $~J_{\rm F\,M}$ $_{\rm A\,F}$ S $_{\rm F\,M}$ $_{0}H_{EB}M_{FM}t_{FM} = 0.79 \text{ erg/cm}^{2}$, close to that $S_{AF} =$ previously found in sim ilar system s¹⁴. However, the onset H_{FC} for positive EB in this case is about two orders of m agnitude sm aller than previously found 15 . This very small H_{FC} necessary for positive EB challenges the present interpretation of positive EB.

O ne possible explanation for these observations considers pinned uncom pensated m om ents in the bulk of the AF.N eutron scattering results show that parallelAF dom ain walls can form between the bulk and interfacialAF m om ents when the interfacial m om ents are m ore strongly coupled with the FM ¹⁶. For sm all (large) cooling eds, interfacial AF m om ents need to orient in the negative (positive) direction to establish negative (positive) EB. H ere, antiferrom agnetic interfacial coupling is assumed. H owever, bulk AF m om ents far away from the interface are dom inated by the applied eld and align parallel to it. This is independent from the orientation of the interfacial AF m om ents. Therefore, a parallel AF dom ain wall form s in case of negative EB, but not for positive EB.

A second scenario considers a parallel dom ain wall in

the FM .Spontaneous rotation found previously supports this possibility⁹. When cooling down, such a domain wall occurs in positively exchange biased thick FM s because the antiferrom agnetic interfacial coupling locks interfacial FM moments in the negative direction while FM moments far from the interface only sense the external $eld^{17,18}$. W ith the inclusion of the parallel AF and/or FM domain wall energies, the sign of exchange bias is no longer determined simply by the competition between $\not E_{int}j$ and $\not E_{AF \ Z \ eem \ an} \ j$ and the paradox $jn_{FM} \ j << jn_{AF} \ j$ can be avoided. However, detailed calculations of the di erent energies involved in negative and positive EB are necessary to explicitly develop the pertinent relationships.

The observed slow dynam ics may arise from the com petition of these energies around $T_{\rm N}$, which also determ ine the sign of EB while the AF order is established. The competition of these energies may result in multiple local energy m in in a that are separated by signi cant an isotropy barriers. These barriers grow larger com pared with $k_B T$ with decreasing tem perature, and the time it takes for the system to evolve into a lower energy state exponentially increases. Therm altraining allows the system to seek out the global energy minimum because the FM dom ains are approxim ately unchanged with tem perature, but the AF order is cyclicly perturbed. A fler cooling to $T_x < T_N$ for the st time, the AF orders, and a portion of the originally saturated FM spontaneously reverses because $f_{int} j > f_{FM} Z_{eem an} j$. Next, the AF becom es disordered when warm ed to $T_x > T_N$ with the FM dom ains relatively unchanged. Subsequent cooling causes the population of positive EB regions to increase

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because the FM m om ents associated with the dom ain walls deviate from the eld direction. This results in a sm aller coupling energy with the AF, m aking it easier for the AF m om ents to align with the eld. This gives rise to a larger fraction of the sam ple that show spositive EB, and thereby increases the m agnetization reversalm agnitude. This process is successful because the FM dom ain wall width is an order of m agnitude larger than the AF dom ain wall width. The details of the tim e-dependent reversal, what determ ines the system ground state, and the various paths to reach this state are not presently understood.

In sum m ary, two di erent cooling protocols revealed that spontaneous m agnetization reversal in exchange biased heterostructures is strongly tim e-dependent. Slow er cooling speeds and longer waiting tim es around $T_{\rm N}$ lead to larger m agnetization reversal. Therm all training was discovered by cycling the sam ple tem perature about $T_{\rm N}$, causing the FM to reverse successively with each cycle. This e ect re ects the incremental conversion of negative to positive EB regions. These results suggest that spontaneous reversal is therm odynam ically stable rather than m etastable, contradicting our present understanding of positive EB. A dditional energy term s that describe parallel dom ain walls in the antiferrom agnet and/or ferrom agnet are necessary to explain these results, and to re ne positive exchange bias m odels.

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